			REFERENCE				
PREPARED BY:	DATE:		SPEC.NoDG-958041				
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APPROVED BY:	DATE:	ELECTRONIC COMPONENTS (GROUP 'AGE 8 Pages				
_		SHARP CORPORATION	REPRESENTATIVE DIVISION				
M. Abe	Aug. 10, 95	SPECIFICATI	O N OPTO-ELECTRONIC DEVICES DIV.				
	DEVICE S	PECIFICATION FOR GaAsP/Gap Red Chip LED Device					
	MODEL No	LT1D67A					
	`						
for any and not (Notice)	tes etc. in these specification is device is designed to the specification of the specificati	For use in the following applications; udio visual equipment • Home appl equipment (Terminal) "Measuring ec • Computer cations, if there is applicable to the it	the absolute maximum ratings d below for actual use of this device.				
(2) Th	ne appropriate measures, fety design of overall s and safety in the fu	such as fail-safe design and redundant system and equipment, should be taken unction and precision when this device	t design considering n to ensure the reliability is used for equipment, such as;				
	Transportation co "Traffic signal other safety equip	ontrol and safety equipment (aircraft, • Gas leakage sensor breaker • Fire brent, etc.	train, automobile etc.) oox and burglar alarm box				
(3) Ple	ease do not use for the ad safety in function an	uses mentioned below which require d precision	extremely high reliability				
	• Space equipment ["Nuclear power conf	"Telecommunication equipment (Trunk) rol equipment Medical equipment etc					
(4) Co	ntact and consult with use this device for a	a Sharp representative if there are any applications listed above or applica-	y questions when intending able to the listed above,				
3. Contact	and consult with a Sha	rp representative, in advance, if there	any questions about this device.				
CUSTO	OMER'S APPROVAL	DATE PRES BY	ENTED M. Abe				
DATE			M. Abe Department General Manager of				
ВУ		 	Engineering Dept., III Opto-Electronic Devices Div. ELECOM Group				
		9	SHARP CORPORATION				



LTID 67A

This data sheet is to introduce the light emitting diode device Model No. LT1D67A, delivered to

I.Structure and characteristics

Structure: GaAsP/GaP red chip LED dev. ce

Outline dimensions and pin connections See page 2

Taping specification: See page 345 6

Packing specification: See page 7
Soldering method: See page 8

2. Absolute ● aximum ratings

(Ta = 2.5 %)

2. Hobolate • axiiiiaiii t	\ 1 u	<u> </u>		
Parameter			Value	Unit
Power dissipation			8 4	□W
Continuous forward	current	IF	3 0	шA
Peak forward current	(Note 1)	IFM	5 0	na A
Derating factor	DC	_	0.40	□ A/Y
	. Pulse	_	0.67	mA∕°C
Reverse voltage		V _R	5	V
Operating temperatur	e	T opr	- 30~+ 85	$^{\circ}$
Storage temperature		Tstg	-40~+100	$^{\circ}$ C

(Note 1) Duty ratio = 1/10, Pulse width = (.). 1 ms

. Electro optical characteristics

(Ta = 2.5 %)

Parameter	Symbol	Conditions	Min.	Тур,	Max.	Unit
Forward voltage	V _F	$I_F = 20 \text{ mA}$	_	2.0	2.8	٧
Luminous intensity	I v	l j				
(Note 2)			2.7	8.8	-	mcd
Peak emission	λр					
wavelength			_	635	' -	næ
Spectrum radiation	Δλ					
bandwidth				35		nma
Reverse current	IR	$V_R = 4 V$	_	_	10	μΑ
Terminal capacitance!	Ct	V = 0V, $f = 1MHz$ I	-	20	_	рF

(Note 2) Torelance: ±15%

4. Luminous intensity rank

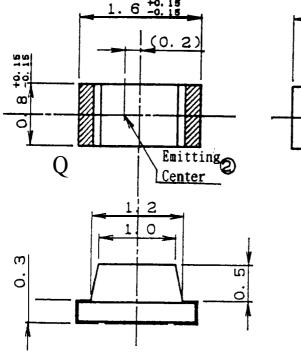
 $(Ta = 25^{\circ}C)$

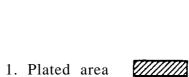
R	ank:Lumin	nous	intensity	Unit	Condition
Α	2.'7	~	5.2		
В	3.9	~	7.5		IF = 20mA
С	5 . 6	~	10.8	mcd	tolerance; ±15%
D	8 . 1	>	15.6		
Е	11.6	~	22.5		

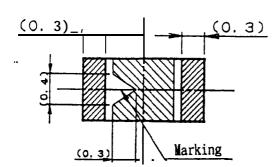
(Note3) Measured by SHARP EG&GMODEL550 (Radiometer/Photometersys tern)

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2. Pin Conection

Resist area

- ① Cathode
- 2 Anode

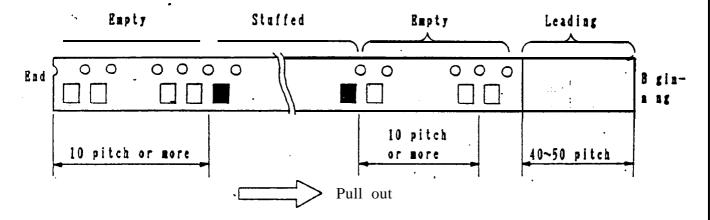
3. Unspecif ed tol. to be ± 0.1

	·												
適用機能 AP	PLICA	BLE A	ODBL	尺度	SCALE	単位	UNIT				,		
LT				20	/1	г	nm	88	ſ⊟ da′	LB	*5118Z5	REVISE	相当CHNG
X THICKNE	SS 🗐	文 PII	CBS	材質 мл′	TBRIAL	仕上	FINISH						1
						Αu&	つき	名文	称 WB			dimensio connect	
日付 DATE	1995.	4	• 25	シャー	プ株式会	往電子部	哈本菜本部		-1,				
CEST SHE	模図 CBE CK	模図	748	オプトラ	デバイス	(事)第	3技術部	cc	DB				
岡崎岡	層	<u> </u>		SHAR	RERCO	4 GROUP	ICES DIV	N.	器 AWING	No.	50	6040	26B
			النابا										

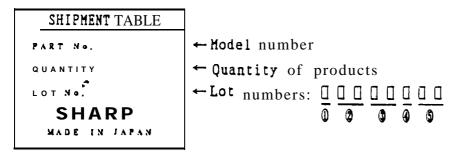


Taping Specification

- 1. This data sheet it to introduce the taping specification of LED device, model No. LT1 D 67A
- 2. Taping specification
- 2.1 Taping specification



2.2 Shipment table



- *:Lot indication
 - ① Production plant code(to be indicated alphabetically)
 - Production lot(single or double figures)
 - **9** Year of production(the last two figures of the year)
- Month of production

(to be indicated alphabetically with January corresponding to A)

Date of production(01~31)

MODEL No. '

LT1D67A

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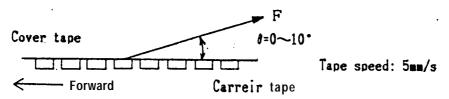
2.3 Related ● atters

2.3.1. Packing

There should not be sissing above continuous three products.

2.3.2. Tape strength

I) Cover "tape strength against peel ing: F = 0.1~0.8N(0=10° or less)



2) Tape strength against bending

The radius of bending circle should be 30mm or more.

If it is less than 30mm, the cover tape may peel.

- 2.3.3. Taking out of products
 - 1) Products should be easily taken out.
 - 2) Products should not be attached to the cover tape at peeling.
- . 2.3.4.. Jointing of tape

There should not be joint of cover tape or carrier tape.

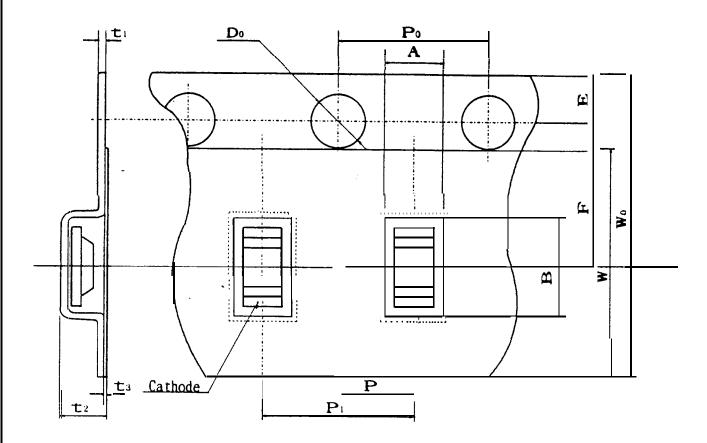
3. Quantity per reel

Average: 4,000 pcs. per reel



4-1. Taping

4-1-1, Shape and dimension of tape(TYP.)

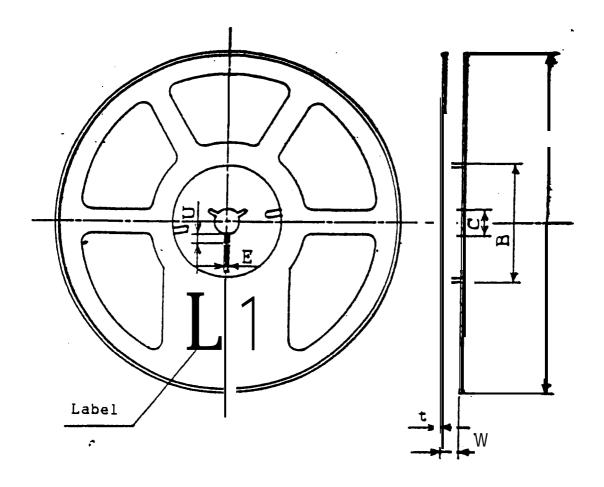


Parameter	4	Symbol	Dimension	Remarks
Concave square	Vertical	A	1. Omm	Dimension excludes corner R
hole for part	Horizontal	В	1. 9mm	at inside bottom
insertion	Pitch	P ₁	4. Omm	
Round	Diameter	D0	1. 5 mm	
sprocket	Pitch	P _o	4. Omm	Accumulated error ±0.5mm/10 pitch
hole	Position	E	1. 75mm	Distance between tape edge and hole center
Center to cen-	Vert.dire	P ₂	2. Omm	Center line of the concave square hole and
ter dimension	Hori.dire	F	3. 5mm	round sprocket hole
Cover tape	Width	W,	5. 5mm	
	Thickness	t ₃	O. 1mm	
Carrier tape	Width	Wo	8. Omm	
	Thickness	t ₁	O. 2mm	
Thickness of the entire unit		t ₂	1.2mm	With cover tape and carrier tape combined

Material: Carrier tape...PET.Covertape...Polyester



4-1-2. Shape and dimension of reel (TYP.)



Parameter			Symbol	Dimension	Remarks	
	Diameter		A	ø 178mm,		
Flange	e Thickness		t	1. 5mm		
	Inner space	e direction	W	1 Omm	Dimension of shaft core	
	External di	ameter	В	ø 60mm		
Hub	Spindle hole diameter Key slit Width		С	ø 13mm		
			Е	2.0mm		
	Depth		u	4.5mm		
Notation for part name etc.			Labeling on one side of flange.			
			(Part na	ame,quantity	(lot No.)	

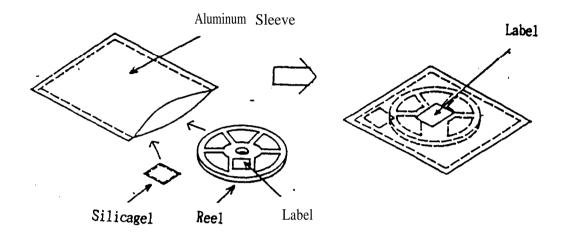
★ Material: Reel...Polystyrene

•. .



Packing < pacification

In order to avoid the absorption of humidity in transport and storage, **the devices** are "packed in aluminum sleeve,



1. Storage Conditions

The storage should be done under following conditions:

Temperature 5 to 30°C

Humidity less than 60%RH

- 2. Treatment after Opening
- 1) Please make a soldering within 2 days after opening under following conditions:

Temperature 5 to 30t

Humidity less than 60%RH

- 2) In case the devices are not used for a long time after opening, the storage in dry box is recommendable. Or it is better to repack the devices with a desiccative by the sealer and put them in the same storage conditions as 6-1. Then they should be used within 2 weeks.
- 3) Please **make a** soldering after a following baking treatment if unused term should be over the conditions of 2).

Recommendable Conditions:

(1) in taping

Temperature 60°C Time 90 to 100 Hours

(2) in individual (on PWB or metallic tray)

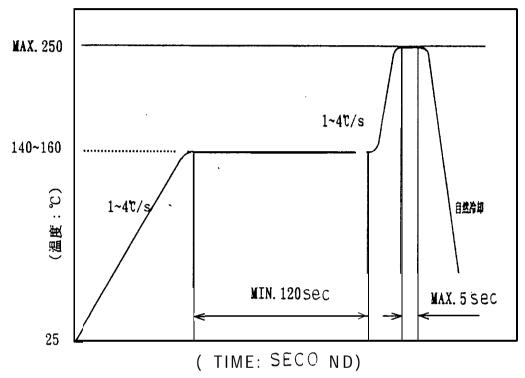
Temperature 110° Time 3 to 4 Hours

Mounting precautions

1, Soldering

1-1 Reflow soldering

To be done-under the following condition.



Recommendable Thermal Model

1-2 Reflow soldering precautions
Second time soldering should be done within 8

Second time soldering should be done within 8 hours after the first one is finished. (Storage condition: at 30C, RH < 60%)

2. Soldering iron method At 00C within seconds

When using a soldering iron, care must be taken not to damage the package (Payattion not to allow any undue stress or heat on package.)